Energy level lifetimes in the single-molecule magnet Fe₈: Experiments and simulations

S. Bahr, ¹ K. Petukhov, ^{1,*} V. Mosser, ² and W. Wernsdorfer ¹ Institut Néel, CNRS/UJF, Boîte Postale 166, 38042 Grenoble Cedex 9, France ² Itron France, 76 avenue Pierre Brossolette, 92240 Malakoff, France (Received 27 September 2007; published 4 February 2008)

We performed pump-probe measurements on the single-molecule magnet Fe₈ with microwave pulses having a length of several nanoseconds. The microwave radiation in the experiments is located in the frequency range between 104 and 118 GHz. The dynamics of the magnetization of the single Fe₈ crystal is measured using micrometer-sized Hall sensors. This technique allows us to determine the level lifetimes of excited spin states that are found to be in good agreement with theoretical calculations. The theory to which we compare our experimental results is based on a general spin-phonon coupling formalism, which involves spin transitions between nearest and next-nearest energy levels. We show that good agreement between theory and experiments is only obtained when using both the $\Delta m_S = \pm 1$ transition as well as $\Delta m_S = \pm 2$, where Δm_S designates a change in the spin quantum number m_S . Temperature dependent studies of the level lifetimes of several spin states finally allow us to experimentally determine the spin-phonon coupling constants.

DOI: 10.1103/PhysRevB.77.064404 PACS number(s): 75.50.Xx, 75.60.Jk, 75.75.+a, 76.30.-v

I. INTRODUCTION

Single-molecule magnets (SMMs) are a novel class of materials, where almost identical magnetic molecules are regularly assembled in large crystals. Every molecule contains a well-defined structure of superexchange-coupled magnetic metal ions. At low temperature, the relative orientation of the strongly coupled, intramolecular spins is locked and each molecule can be described by one single, collective spin S. This approximative description of the molecule is called giant spin approximation. 1-6 SMMs have attracted much research interest in the last decade because of their quantum properties that can be studied even on a macroscopic scale.^{7–11} In particular, quantum mechanical effects, such as quantum tunneling of magnetization through the magnetic anisotropy barrier, revealed the potential use of SMMs in the field of quantum computation and data storage. 12-14 SMMs are also a convenient model system to study the dynamics and the interaction of a well-defined spin system with its environment. Especially, interactions with nuclear spins or lattice vibrations in the crystal are a source of decoherence and therefore of particular interest. 15-18 The use of microwave radiation that induces transitions between different spin states can provide a direct access to the spin dynamics of the molecules. Such experiments employing continuous-wave electron spin resonance^{4,19-21} and pulsed microwaves time-resolved magnetometry^{11,22-32} were performed during the last years in order to get a better understanding of the spin relaxation time T_1 and decoherence time T_2 . These parameters were determined mainly by the use of detailed linewidth analysis of absorption peaks or direct relaxation measurements in the time domain. 11,22-32 A possibility to overcome various experimental difficulties (such as extensive heating of the sample by long microwave pulses, phonon-bottleneck effects, and thermal relaxation) can be the use of very short microwave pulses or sequences of pulses on a nanosecond scale.

Concerning fast spin relaxation times of the order of several hundreds of nanoseconds, we recently proposed a pump-

probe technique employing a sequence of microwave pulses to resolve the basic mechanisms of spin-phonon coupling in Fe₈. ³² This kind of technique employs very short microwave pulses, and therefore thermal heating of the material is very small. The time resolution of the dynamical processes obtained by pump-probe experiments can be as fast as several nanoseconds, and as a consequence, we think they are much more precise and appropriate than direct relaxation measurements in the time domain.

In this paper, we study the spin dynamics of the SMM $Fe_8O_2(OH)_{12}(tacn)_6$, hereafter called Fe_8 .³³ This molecule contains eight Fe(III) ions with spins s=5/2. These spins are strongly superexchange coupled, forming a spin ground state S=10, and the molecule can be described at low temperature by an effective Hamiltonian⁴

$$\mathcal{H} = -DS_{z}^{2} + E(S_{y}^{2} - S_{y}^{2}) + \mathcal{O}(4) + g\mu_{B}\vec{S} \cdot \vec{H}. \tag{1}$$

 \vec{H} is the applied magnetic field, $\mathcal{O}(4)$ contains fourth order terms of spin operators, $g \approx 2$ represents the gyromagnetic factor, and μ_B denotes the Bohr magneton. The anisotropy parameters D = 0.275 K and E = 0.046 K have been determined by various experimental methods, such as high-frequency electron paramagnetic resonance techniques, frequency domain magnetic resonance spectroscopy, and neutron spectroscopy, and they yield similar results. 4,6,10,20,34 The nondiagonal terms in the Hamiltonian are responsible for the tunneling processes between spin states, whereas D defines the anisotropy barrier of approximately 25 K.

This paper presents pump-probe measurements on the SMM Fe_8 . We focus our work on the level lifetimes of different spin states as a function of temperature and applied magnetic field. In Sec. II, we describe the experimental setup and the principle of the pump-probe technique. In Sec. III, we present the experimental results of the pump-probe experiments that will be compared in Sec. IV to simulations based on a general spin-phonon coupling theory. The experimental data are discussed in Sec. V, and Sec. VI finally gives some concluding remarks.

II. EXPERIMENTAL TECHNIQUES

The measurements are performed using a commercial $16\ T$ superconducting solenoid and a cryostat in the temperature range from $1.4\ to\ 15\ K$ with high temperature stability. The magnetization of the Fe_8 sample is measured with a Hall magnetometer.

The Hall bars were patterned by Thales Research and Technology (Palaiseau), using photolithography and dry etching, in a delta-doped AlGaAs/InGaAs/GaAs pseudomorphic heterostructure grown by Picogiga International using molecular beam epitaxy. A two-dimensional electron gas is induced in the 13 nm thick $\rm In_{0.15}Ga_{0.85}As$ well by the inclusion of a Si delta-doping layer in the graded $\rm Al_xGa_{1-x}As$ barrier. All layers, apart from the quantum well, are fully depleted of electrons and holes. The two-dimensional electron gas density n_s is about $8.9\times10^{11}~\rm cm^{-2}$ in the quantum well, corresponding to a sensitivity of about 700 Ω/T , essentially constant below $-100~\rm ^{\circ}C$.

The sample is placed on top of the $10\times10~\mu\text{m}^2$ Hall junction with its easy axis approximately parallel to the magnetic field of the solenoid. The Hall voltage, being about proportional to the magnetization and of the order of magnitude of several microvolts, is amplified by a low noise preamplifier with large frequency bandwidth $f_{BW}>100~\text{MHz}$. The time-resolved magnetization measurements were averaged typically over 1000 events.

Microwaves are generated by two continuous wave, mechanically tunable Gunn oscillators in a frequency range from 97 to 119 GHz. Pulses are generated using two SPST fast PIN diode switches (switching time less of than 3 ns) triggered by a commercial pulse generator. An oversized circular waveguide of 10 mm diameter leads the microwaves into the cryostat to the sample.

The pump-probe technique uses a sequence of two microwave pulses with pulse lengths as short as 20 ns. The two microwave pulses p_1 and p_2 are delayed in time and they excite spins from different levels m_S (Fig. 1). In general, the pump-probe experiment involves three energy levels m_S , m_S+1 , and m_S+2 . The resonant frequency between m_S and m_S+1 , as well as that between m_S+1 and m_S+2 , depends on the applied magnetic field $\mu_0 H_z$. We carried out pump-probe experiments at four different magnetic field values using two different pairs of microwave frequencies. At a magnetic field $\mu_0 H_z = 0.12 \text{ T} (\mu_0 H_z = 0.48 \text{ T})$, we used the resonant frequencies f=104 GHz and f=115 GHz to study the level lifetime of the level $m_S = -9$ ($m_S = -8$). At a magnetic field $\mu_0 H_z$ =0.2 T ($\mu_0 H_z$ =0.56 T), we used the resonant frequencies f = 107 GHz and f = 118 GHz to study the level lifetime of the level $m_S = -9$ ($m_S = -8$). During the pump-probe experiments, the magnetization of the sample, which is directly proportional to the Hall voltage, is recorded as a function of time for fixed delay Δt between the two microwave pulses (Fig. 2). The Hall voltage V is a precise measure of the magnetization of the sample. As the temperature in the crystal is hardly affected by the very short microwave pulses, we can suppose that thermal activation of spins to higher levels is very weak. Therefore, ΔV , as defined in Fig. 2, is proportional to the number of spins excited by the two microwave

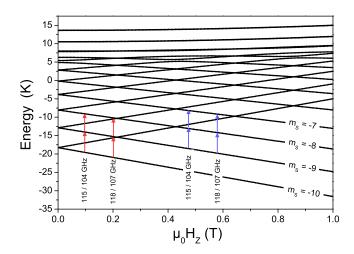


FIG. 1. (Color online) Zeeman diagram of the SMM Fe₈ with some microwave induced transitions between spin states. For a certain given combination of two microwave frequencies, i.e., 104 and 115 GHz, one can find a magnetic field value where the higher microwave frequency excites spins from a level m_S to m_S+1 and the lower frequency is in resonance between m_S+1 and m_S+2 .

pulses to higher energy levels. In particular, the decrease of the magnetization due to the second microwave pulse p_2 is proportional to the amount of spins in the level m_S+1 . When plotting the magnetization decrease, which is proportional to ΔV , as a function of the delay time Δt between the two microwave pulses, we get information about the depopulation of the level m_S+1 , and therefore we can determine the level lifetime of the level m_S+1 . This decay of the population of the level m_S+1 is mainly due to spin-phonon interaction in the temperature range of our experiments.

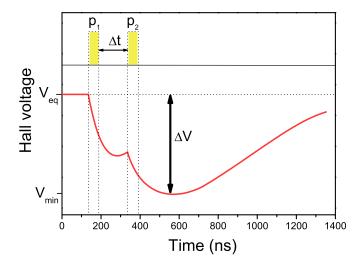


FIG. 2. (Color online) Sketch of a typical pump-probe experiment at low temperature. Two microwave pulses p_1 and p_2 with different frequencies and pulse lengths of typically less than 50 ns are separated by a delay Δt . They excite the spin system and the magnetization of the sample, i.e., the Hall voltage decreases, reaches a minimum, and relaxes back to the equilibrium value. The Hall voltage amplitude $\Delta V = V_{eq} - V_{min}$ depends on the amount of spins excited by the two microwave pulses.

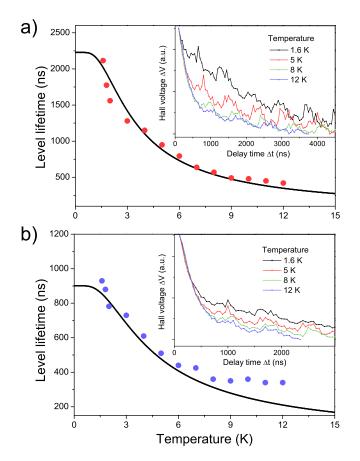


FIG. 3. (Color online) Experimental results of the pump-probe experiments with frequencies of 104 and 115 GHz. The pump pulse has a length of 40 ns, whereas the probe pulse has a length of 20 ns. (a) Measurements at a magnetic field of $\mu_0 H_z$ =0.12 T, i.e., spin transitions between the states m_S =-10, m_S =-9, and m_S =-8. The inset shows ΔV as a function of the delay time between the two pulses for different temperatures in the range from 1.6 to 12 K. The characteristic relaxation time of $\Delta V(\Delta t)$ is shown as a function of the temperature. (b) Measurements at a magnetic field of $\mu_0 H_z$ =0.48 T, i.e., spin transitions between the states m_S =-9, m_S =-8, and m_S =-7. The inset shows ΔV as a function of the delay time between the two pulses for different temperatures in the range from 1.6 to 12 K. The characteristic relaxation time of $\Delta V(\Delta t)$ is shown as a function of the temperature. We find good agreement with theoretical calculation (black lines).

III. MEASUREMENTS

We already showed the possibility to investigate level lifetimes with the above described pump-probe technique elsewhere.³² This present publication is a substantial extension of previous work. In particular, we compare pump-probe measurements at several magnetic fields and with different microwave frequencies.

The insets of Fig. 3 show the Hall voltage decrease ΔV as function of the delay Δt between the microwave pulses with frequencies f_1 =115 GHz and f_2 =104 GHz. The relaxation of ΔV is fitted with a single exponential function, and the characteristic relaxation time is plotted as a function of the temperature in the range 1.6–12 K. The relaxation time depends on the spin level involved in the experiment.

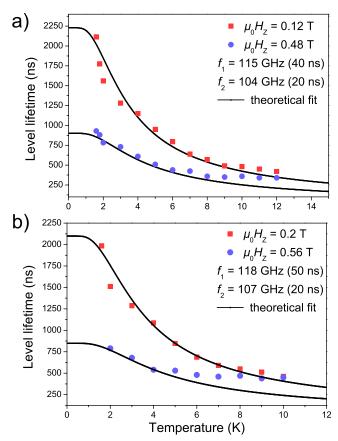


FIG. 4. (Color online) Summary of various different pumpprobe measurements employing two different pairs of microwave frequencies. (a) With the combination 104 GHz/115 GHz, the level lifetime of m_S =-9 can be probed at μ_0H_z =0.12 T, whereas the lifetime of the m_S =-8 states can be probed at μ_0H_z =0.48 T. (b) The combination 107 GHz/118 GHz allows us to determine the level lifetime of m_S =-9 and m_S =-8 at magnetic fields of μ_0H_z =0.2 T and μ_0H_z =0.56 T, respectively. The level lifetime measurements are in good agreement with theoretical simulations (black lines).

When working at a magnetic field $\mu_0 H_z = 0.12$ T, we study the level lifetime of $m_S = -9$ [Fig. 3(a)]. The relaxation time is at low temperature around 2 μ s, whereas for higher temperatures, it is around 500 ns. For the level $m_S = -8$ at a magnetic field $\mu_0 H_z = 0.48$ T, we observe at low temperature a relaxation time of 1 μ s and for higher temperatures less than 400 ns [Fig. 3(b)].

Figure 4 shows two generic plots of the relaxation times as a function of temperature and the four different magnetic field positions as shown in Fig. 1. In Fig. 4(a), the relaxation time is plotted as a function of the temperature for the microwave frequencies f_1 =115 GHz and f_2 =104 GHz. The measurements on the spin level m_S =-9 yield significantly longer relaxation times than measurements on the level m_S =-8.

In Fig. 4(b), the relaxation time is plotted as a function of the temperature for the microwave frequencies f_1 = 118 GHz and f_2 =107 GHz. The results are similar to the ones obtained with f_1 =115 GHz and f_2 =104 GHz. Note that, in particular, the lifetime of the spin level m_S =-9 is

significantly longer than the lifetime of the level $m_S = -8$.

All experimentally obtained level lifetimes are compared to a theoretical model based on general spin-phonon coupling theory. The theoretical calculations of the level lifetimes that are shown in Figs. 3 and 4 (black lines) are performed with one set of parameters that will be detailed hereafter in Sec. IV.

IV. THEORETICAL APPROACH

We follow in this section the theoretical description of spin-phonon coupling in molecular high spin systems first described by Villain *et al.*³⁵ and later extended by Garanin and Chudnovsky³⁶ and Leuenberger and Loss.³⁷

In general, the spin-phonon coupling can induce transitions of the form $\Delta m_S = \pm 1$ and $\Delta m_S = \pm 2$ of the projection of the spin along the z direction, where Δm_S denotes the change of the spin quantum number m_S . For a given spin state m, we therefore obtain four different rate equations concerning phonon-induced transitions $W_{m \to m \pm 1}$ and $W_{m \to m \pm 2}$ to higher- and lower-lying energy levels. A theoretical approach using a generalized master equation which treats phonon-induced spin transitions leads to explicit formulas of these spin-phonon processes, ³⁷

$$W_{m \to m \pm 1} = \frac{g^2 s_{\pm 1}}{12\pi \rho c^5 \hbar^4} \frac{(\epsilon_{m \pm 1} - \epsilon_m)^3}{\epsilon^{\beta(\epsilon_{m \pm 1} - \epsilon_m)} - 1},$$
 (2)

$$W_{m \to m \pm 2} = \frac{17g^2 s_{\pm 2}}{192 \pi \rho c^5 \hbar^4} \frac{(\epsilon_{m \pm 2} - \epsilon_m)^3}{e^{\beta(\epsilon_{m \pm 2} - \epsilon_m)} - 1},$$
 (3)

where g denotes the spin-phonon coupling constant, $s_{\pm 1} = (s \mp m)(s \pm m+1)(2m \pm 1)^2$, $s_{\pm 2} = (s \mp m)(s \pm m+1)(s \mp m-1)(s \pm m+2)^2$, $\rho = 1.9 \times 10^3$ kg/m³, $\beta = 1/k_BT$, and c is the speed of sound. It has been shown that the spin-phonon coupling constants g_i are all of the same order of magnitude and their magnitude has shown to be similar to the anisotropy energy D in comparable molecular systems.³⁷

Finally, the lifetime τ_m of a spin level m is defined by

$$1/\tau_m = W_{m \to m+1} + W_{m \to m-1} + W_{m \to m+2} + W_{m \to m-2}.$$
 (4)

The lifetimes of the different spin levels m show large differences at low temperature. The magnitude of the level lifetimes of excited levels is much smaller than the ground state level lifetime. Additionally, all the level lifetimes exhibit a strong temperature dependence.

In Fig. 5, several level lifetimes are plotted as a function of the temperature. In the two panels, we compare directly the influence of the $\Delta m_S = \pm 2$ process on the different level lifetimes. As can be seen in Eqs. (2) and (3), the level lifetimes are very sensitive to variation of the speed of sound c or the spin-phonon coupling constants. They also depend strongly on the relative magnitude of the $\Delta m_S = \pm 1$ and $\Delta m_S = \pm 2$ processes. In fact, the $\Delta m_S = \pm 2$ process gives a big contribution to the excited level lifetimes, and at low temperature, this process strongly influences the spin dynamics and shortens the level lifetimes. This property can be seen clearly when comparing the level lifetimes of the excited spin state m=-8 in Figs. 5(a) and 5(b). The additional Δm_S

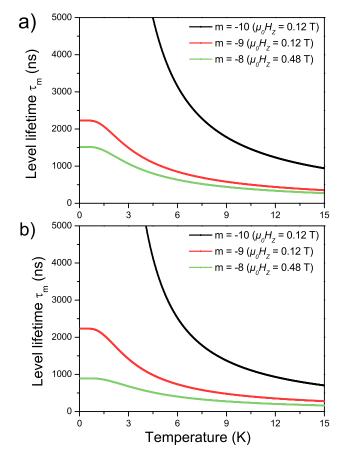


FIG. 5. (Color online) Theoretical calculations of the level lifetimes of three different spin states m=-10, m=-9, and m=-8. The magnetic field H is chosen according to our pump-probe experiments with 115 and 104 GHz [Fig. 4(a)]. In (a), we only considered the $\Delta m_S = \pm 1$ process, whereas in (b), we calculated the level lifetimes according to Eq. (4) using the $\Delta m_S = \pm 1$ and $\Delta m_S = \pm 2$ spin-phonon processes. Note that the level lifetimes of m=-9 and m=-8 shown in (b) correspond to the theoretical simulation in Fig. 4(a).

= ± 2 process reduces the level lifetimes at low temperature by nearly a factor of 1.5.

V. DISCUSSION

The presented pump-probe experiments using nanosecond microwave excitations allow us to determine directly energy level lifetimes. Figures 3 and 4 show the obtained level lifetimes of different energy levels at different magnetic fields and as a function of the temperature. The obtained energy level lifetimes for the levels m=-9 and m=-8 are in the range between 2.2 μ s and 300 ns and the dependence on temperature and magnetic field can be well reproduced by general spin-phonon coupling theory. However, for higher temperatures (T > 8 K), we observe deviations from the theoretical calculations, especially for the measurements on the m=-8 state. This might be due to the giant spin approximation, i.e., due to disregarding of higher spin multiplets that start to get populated at higher temperatures (the S=9 multiplet is located at about $\Delta E \approx 24$ K above the ground state multiplet²¹).

In addition, the level lifetimes seem not to be influenced very much by the presence of a proximate level anticrossing (as in the case of measurements at 0.2 T).³² In fact, one could have supposed that the relaxation of magnetization gets accelerated when additional relaxation paths get available. However, we do not notice any dramatic changes in the level lifetimes in our experiments when measuring near a level anticrossing. As a consequence, the dominant relaxation mechanism seems to be based on spin-phonon interaction in the temperature range we investigated.

In particular, the prefactor of the simplified spin-phonon rate equations (2) and (3) depends on the spin-phonon coupling constant and on the transverse speed of sound in the bulk material. Unfortunately, our measurements do not allow us to fit both of these parameters independently. The speed of sound in Fe₈ has been studied by several techniques, such as specific heat measurements and NMR.^{38–41} The published results differ a lot and range from c=670 m/s to c=1500 m/s. Nevertheless, our measurements allow us to determine the ratio g^2/c^5 , where g is the spin-phonon coupling constant and c the speed of sound. We find a value of $\frac{g^2}{c^5} \approx 1 \times 10^{-17} \text{ K}^2 \text{s}^5/\text{m}^5$, which leads to a spin-phonon coupling constant g in the range between 0.036 and 0.275 K (when c is chosen in the range mentioned above).

Recent publication in the field suggests describing the spin-phonon interaction only on the basis of the $\Delta m_S = \pm 1$ process and neglecting completely the $\Delta m_S = \pm 2$ processes.²⁹ This would result in substantially longer level lifetimes of the excited spin states and therefore slowdown the spin dynamics. In particular, Fig. 5 shows that the $\Delta m_S = \pm 2$ spin-phonon process has great influence in the low temperature behavior of the level lifetimes. Especially for the level m=-8 and higher excited levels, this supplementary

process gives rise to a significant reduction of the level lifetime compared to the m=-9 level. When only taking $\Delta m_S = \pm 1$ spin phonon relaxation process, the levels m=-9 and m=-8, the difference of their level lifetimes at low temperature decreases significantly. Our experimental results are only well reproduced by spin-phonon coupling theory when using the $\Delta m_S = \pm 1$ and $\Delta m_S = \pm 2$ processes with the choice of parameters as explained above.

VI. CONCLUSION

In conclusion we presented pump-probe experiments on the SMM Fe₈ with pulsed microwaves on a nanosecond scale at frequencies in the range from 104 to 118 GHz. These experiments allowed us to investigate the level lifetimes of excited spin states as a function of temperature and applied magnetic field. Typically, we observe level lifetimes of the order of magnitude of 400 ns up to more than 2 μ s. The temperature dependent measurements presented for the m= -9 and m=-8 energy levels can be explained by a general spin-phonon coupling theory. The fit of our experimental data is consistent with published values for the speed of sound and spin-phonon coupling constants.

ACKNOWLEDGMENTS

We acknowledge motivating discussions with J. R. Friedman and E. M. Chudnovsky. The sample for the investigations was kindly provided by A. Cornia. This work is partially financed by EC-RTN-QUEMOLNA Contract No. MRTN-CT-2003-504880 and MAGMANet. The authors thank E. Eyraud, J.-S. Pelle, and J. Florentin for their useful technical contributions to this work and A.-L. Barra for scientific support.

^{*}Present address: Physikalisches Institut III, Universität Erlangen-Nürnberg, Erwin-Rommel-Strasse 1, D-91058 Erlangen, Germany

¹R. Sessoli, H. L. Tsai, A. R. Schake, S. Wang, J. B. Vincent, K. Folting, D. Gatteschi, G. Christou, and D. N. Hendrickson, J. Am. Chem. Soc. 115, 1804 (1993).

²R. Sessoli, D. Gatteschi, A. Caneschi, and M. A. Novak, Nature (London) **365**, 141 (1993).

³M. Novak and R. Sessoli, in *Quantum Tunneling of Magnetization-QTM94*, edited by L. Gunther and B. Barbara, NATO Advanced Studies Institute, Series E: Applied Sciences (Kluwer, Dordrecht, 1995), Vol. 301, pp. 171–188.

⁴A.-L. Barra, P. Debrunner, D. Gatteschi, Ch. E. Schulz, and R. Sessoli, Europhys. Lett. **35**, 133 (1996).

⁵S. M. J. Aubin, N. R. Dilley, M. W. Wemple, M. B. Maple, G. Christou, and D. N. Hendrickson, J. Am. Chem. Soc. **120**, 839 (1998).

⁶R. Caciuffo, G. Amoretti, A. Murani, R. Sessoli, A. Caneschi, and D. Gatteschi, Phys. Rev. Lett. **81**, 4744 (1998).

⁷J. R. Friedman, M. P. Sarachik, J. Tejada, and R. Ziolo, Phys. Rev. Lett. **76**, 3830 (1996).

⁸L. Thomas, F. Lionti, R. Ballou, D. Gatteschi, R. Sessoli, and B.

Barbara, Nature (London) 383, 145 (1996).

⁹C. Sangregorio, T. Ohm, C. Paulsen, R. Sessoli, and D. Gatteschi, Phys. Rev. Lett. **78**, 4645 (1997).

¹⁰W. Wernsdorfer and R. Sessoli, Science **284**, 133 (1999).

¹¹L. Sorace, W. Wernsdorfer, C. Thirion, A.-L. Barra, M. Pacchioni, D. Mailly, and B. Barbara, Phys. Rev. B 68, 220407(R) (2003).

¹²M. N. Leuenberger and D. Loss, Nature (London) **410**, 789 (2001).

¹³ F. Troiani, A. Ghirri, M. Affronte, S. Carretta, P. Santini, G. Amoretti, S. Piligkos, G. A. Timco, and R. E. P. Winpenny, Phys. Rev. Lett. **94**, 207208 (2005).

¹⁴A. Ardavan, O. Rival, J. J. L. Morton, S. J. Blundell, A. M. Tyryshkin, G. A. Timco, and R. E. P. Winpenny, Phys. Rev. Lett. 98, 057201 (2007).

¹⁵N. V. Prokof'ev and P. C. E. Stamp, Phys. Rev. Lett. **80**, 5794 (1998).

¹⁶W. Wernsdorfer, T. Ohm, C. Sangregorio, R. Sessoli, D. Mailly, and C. Paulsen, Phys. Rev. Lett. 82, 3903 (1999).

¹⁷P. C. E. Stamp and I. S. Tupitsyn, Phys. Rev. B **69**, 014401 (2004).

¹⁸A. Morello, P. C. E. Stamp, and I. S. Tupitsyn, Phys. Rev. Lett. 97, 207206 (2006).

- ¹⁹S. Hill, J. A. A. J. Perenboom, N. S. Dalal, T. Hathaway, T. Stalcup, and J. S. Brooks, Phys. Rev. Lett. **80**, 2453 (1998).
- ²⁰ A. Mukhin, B. Gorshunov, M. Dressel, C. Sangregorio, and D. Gatteschi, Phys. Rev. B 63, 214411 (2001).
- ²¹D. Zipse, J. M. North, N. S. Dalal, S. Hill, and R. S. Edwards, Phys. Rev. B **68**, 184408 (2003).
- ²²W. Wernsdorfer, A. Müller, D. Mailly, and B. Barbara, Europhys. Lett. **66**, 861 (2004).
- ²³ M. Bal, J. R. Friedman, Y. Suzuki, K. M. Mertes, E. M. Rumberger, D. N. Hendrickson, Y. Myasoedov, H. Shtrikman, N. Avraham, and E. Zeldov, Phys. Rev. B 70, 100408 (2004).
- ²⁴E. del Barco, A. D. Kent, E. C. Yang, and D. N. Hendrickson, Phys. Rev. Lett. **93**, 157202 (2004).
- ²⁵ K. Petukhov, W. Wernsdorfer, A.-L. Barra, and V. Mosser, Phys. Rev. B **72**, 052401 (2005).
- ²⁶M. Bal, J. R. Friedman, Y. Suzuki, E. M. Rumberger, D. N. Hendrickson, N. Avraham, Y. Myasoedov, H. Shtrikman, and E. Zeldov, Europhys. Lett. 71, 110 (2005).
- ²⁷B. Cage, S. E. Russek, D. Zipse, and N. S. Dalal, J. Appl. Phys. 97, 10M507 (2005).
- ²⁸ M. Bal, J. R. Friedman, E. M. Rumberger, S. Shah, D. N. Hendrickson, N. Avraham, Y. Myasoedov, H. Shtrikman, and E. Zeldov, J. Appl. Phys. **99**, 08D103 (2006).
- ²⁹ M. Bal, J. R. Friedman, W. Chen, M. T. Tuominen, C. C. Beedle, E. M. Rumberger, and D. N. Hendrickson, arXiv:0706.3471 (unpublished).

- ³⁰K. Petukhov, S. Bahr, W. Wernsdorfer, A.-L. Barra, and V. Mosser, Phys. Rev. B **75**, 064408 (2007).
- ³¹G. de Loubens, G. D. Chaves-O'Flynn, A. D. Kent, C. Ramsey, E. del Barco, C. Beedle, and D. N. Hendrickson, J. Appl. Phys. 101, 09E104 (2007).
- ³² S. Bahr, K. Petukhov, V. Mosser, and W. Wernsdorfer, Phys. Rev. Lett. **99**, 147205 (2007).
- ³³ K. Wieghardt, K. Pohl, I. Jibril, and G. Huttner, Angew. Chem., Int. Ed. Engl. 23, 77 (1984).
- ³⁴K. Park, M. A. Novotny, N. S. Dalal, S. Hill, and P. A. Rikvold, Phys. Rev. B **66**, 144409 (2002).
- ³⁵J. Villain, F. Hartman-Boutron, R. Sessoli, and A. Rettori, Europhys. Lett. 27, 159 (1994).
- ³⁶D. A. Garanin and E. M. Chudnovsky, Phys. Rev. B **56**, 11102 (1997)
- ³⁷M. N. Leuenberger and D. Loss, Phys. Rev. B **61**, 1286 (2000).
- ³⁸A. M. Gomes, M. A. Novak, W. C. Nunes, and R. E. Rapp, arXiv:cond-mat/9912224 (unpublished).
- ³⁹Y. Furukawa, K. Kumagai, A. Lascialfari, S. Aldrovandi, F. Borsa, R. Sessoli, and D. Gatteschi, Phys. Rev. B **64**, 094439 (2001).
- ⁴⁰ F. L. Mettes, F. Luis, and L. J. de Jongh, Phys. Rev. B **64**, 174411 (2001).
- ⁴¹M. Evangelisti, F. Luis, F. L. Mettes, R. Sessoli, and L. J. de Jongh, Phys. Rev. Lett. 95, 227206 (2005).